Fabrication of electrochemically-modified BiVO₄-MoS₂-Co₃O₄ composite film for bisphenol A degradation

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ABSTRACT

A new electrochemically-modified BiVO₄-MoS₂-Co₃O₄ (represented as E-BiVO₄-MoS₂-Co₃O₄) thin film electrode was successfully synthesized for environmental application. MoS₂ and Co₃O₄ were grown on the surface of BiVO₄ to obtain BiVO₄-MoS₂-Co₃O₄. E-BiVO₄-MoS₂-Co₃O₄ film was achieved by further electrochemical treatment of BiVO₄-MoS₂-Co₃O₄. The as-prepared E-BiVO₄-MoS₂-Co₃O₄ exhibited significantly enhanced photoelectrocatalytic activity. The photocurrent density of E-BiVO₄-MoS₂-Co₃O₄ thin film is 6.6 times that of BiVO₄ under visible light irradiation. The degradation efficiency of E-BiVO₄-MoS₂-Co₃O₄ for bisphenol A pollutant was 81.56% in photoelectrochemical process. The pseudo-first order reaction rate constant of E-BiVO₄-MoS₂-Co₃O₄ film is 3.22 times higher than that of BiVO₄. And its reaction rate constant in photoelectrocatalytic process is 14.5 times or 2 times that in photocatalytic or electrocatalytic process, respectively. The improved performance of E-BiVO₄-MoS₂-Co₃O₄ was attributed to the synergetic effects of the reduction of interfacial charge transfer resistance, the formation of oxygen vacancies and sub-stoichiometric metal oxides and higher separation efficiency of photogenerated electron-hole pairs. E-BiVO₄-MoS₂-Co₃O₄ is a promising composite material for pollutants removal.

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Introduction

Environmental and resource issues are attracting more and more attentions due to environmental pollution and resource shortage. Emerging contaminants (ECs) such as medicines, cosmetics, endocrine disrupting chemicals, polycyclic aromatic hydrocarbons (PAHs), and so on have potential threats to the environment and human health even at low concentrations due to their stable chemical properties and easy bioaccumulation (Giulivo et al., 2016; Zia et al., 2019; Liu and Zhao, 2020). For example, endocrine disrupting chemicals (EDCs) can cause endocrine imbalances and result in reduced fertility, carcinogenicity and teratogenesis, neurotoxicity and immune diseases (Bui et al., 2016; Wu et al., 2020). Therefore, it is urgent to develop an environment-friendly technology to remove these contaminants.

Solar energy and electric energy, as clean energy, are considered as the most promising energy in the future.
(Fujishima and Honda, 1972; Zhang et al., 2018a). As a green and efficient advanced oxidation process, the photoelectrocatalytic (PEC) technology has attracted much attention because of its excellent performance in rapidly and thoroughly oxidizing organic pollutants (Zhang et al., 2017a). In PEC process, a bias potential is applied to further promote the separation of photogenerated electron-hole pairs of semiconductor electrode, which was confirmed to be superior to single photocatalytic process (Wang et al., 2012, 2015; Cong et al., 2016; Regmi et al., 2019). In addition, the film catalyst fixed on the conductive electrode in PEC process is easier to reuse than the powder catalyst, and can avoid secondary pollution problems. Many semiconductor materials with visible light response have been developed to degrade the contaminants (Guo et al., 2016; Huang et al., 2017; Gauvin et al., 2018; Malathi et al., 2018; Zhang et al., 2018b). Bismuth-based materials, such as BioX (X = Cl, Br, I), Bi2WO6, Bi2O3·CO2 and BiVO4, have attracted researchers’ attentions due to their unique physical properties under visible light irradiation (Chen et al., 2016; Hu et al., 2018; Sun et al., 2019). Among them, BiVO4 is considered to be a good photocatalytic material due to its narrow band gap (2.4 eV) and wide visible wavelength range (Zhu et al., 2018; Regmi et al., 2019). However, the high recombination of photo-induced electrons and holes is an obstacle to the realization of efficient photocatalytic performance. It is an efficient method that coupling two or more semiconductors reduces the recombination of photo-generated electron-hole pairs (Chen et al., 2017).

Molybdenum disulfide (MoS2), as a special layered material, is widely used in various fields due to its small band gap, excellent electron accepting and transporting performance and good stability (Yu et al., 2016). The construction of BiVO4/MoS2 composites could improve the PEC performance of BiVO4 since the band gap position of MoS2 match with BiVO4 (Arora et al., 2016; Pan et al., 2018). However, the activity of binary BiVO4/MoS2 composites is still very low in practical applications. As an important co-catalyst, Co3O4 has the advantages of low cost, good activity and stability, which could significantly improve the photocatalytic activity of the composite materials (Bao et al., 2016; Liu et al., 2011; Mo et al., 2019). Previous studies have shown that the binary heterojunction constructed by adding Co3O4 to BiVO4 can greatly improve the catalytic performance of BiVO4 (Wang and Osterloh, 2014; Li et al., 2019). Therefore, Co3O4 is selected to fabricate a ternary structure with BiVO4/MoS2 to further improve its performance.

In addition, forming sub-stoichiometric metal oxides was confirmed to be more efficient to increase the carrier densities and improve the PEC performance of metal oxides (Wang et al., 2016). Hydrogenation can achieve the sub-stoichiometry by reducing the metal oxides in hydrogen gas at high temperature (Chen et al., 2011; Harthcock et al., 2020). However, high-temperature hydrogenation is energy-intensive and has potential safety risk. Electrochemical modification has been proved to be an effective strategy for obtaining the sub-stoichiometry in the original metal oxide at normal temperatures and pressures (Wang et al., 2017; Cong et al., 2020). It is convenient to control the quantity of sub-stoichiometric metal oxides by adjusting the treatment time and potential in electrochemical modification. Therefore, the preparation of BiVO4-MoS2-Co3O4 thin films modified by electrochemical treatment (represented as E-BiVO4-MoS2-Co3O4) was expected to achieve perfect PEC performance. As far as we know, E-BiVO4-MoS2-Co3O4 has not been reported.

In this study, BiVO4-MoS2-Co3O4 thin film electrode was synthesized by hydrothermal, electrodeposition and calcination methods, and its photocatalytic activity was further improved by electrochemical modification. X-ray diffraction (XRD), X-ray photoelectron spectroscopy (XPS) and scanning electron microscope (SEM) were used to characterize the as-prepared films. PEC properties of E-BiVO4-MoS2-Co3O4 in visible light were studied by linear sweep voltammetry (LSV), Nyquist spectrum and incident monochromatic photon-current conversion efficiency (IPCE). Bisphenol A (BPA) is one of emerging contaminants, which can cause endocrine disorders, and threaten the health of the fetus and children. In addition, cancer and obesity caused by metabolic disorders are also thought to be related to BPA contamination (Liu and Zhao, 2020). Therefore, BPA was selected as colorless model pollutant to study the performance of E-BiVO4-MoS2-Co3O4 in removing refractory pollutants. The effects of photocatalysis (PC), electrocatalysis (EC) and PEC were studied. The degradation experiments were carried out to study the reaction mechanism.

1. Materials and methods

1.1. Chemicals

Bismuth nitrate pentahydrate (Bi(NO3)3·5H2O), ethylene glycol, formamide, acetone, and boric acid (H3BO3) were all obtained from Chengdu Kelong Chemical Reagent Co., Ltd. (Sichuan, China). Di ammoniumthiomolybdate (NH4)2MoS4 was got from Beijing Bailingwei Technology Co., Ltd. (Beijing China). Polyvinyl alcohol (PVA), ammonium metavanadate (NH4VO3), and cobalt nitrate hexahydrate (Co(NO3)2·6H2O) were purchased from Shanghai Macklin Biochemical Co., Ltd. (Shanghai, China). All reagents were used as received without further purification.

1.2. Synthesis of E-BiVO4-MoS2-Co3O4 films

Fluorine-doped tin oxide substrate (FTO, Nippon Sheet Glass Co Ltd) is used as a substrate material for electrode preparation. The FTO (10 mm × 50 mm × 2.2 mm) was ultrasonically cleaned with acetone, ethanol and deionized water for 10 min to remove the impurities on the surface, and then dried in air at room temperature for use. The preparation processes of BiVO4, BiVO4-MoS2, BiVO4-MoS2-Co3O4 and E-BiVO4-MoS2-Co3O4 films were shown in Appendix A Fig. S1.

(1) Preparation of BiVO4 film: 0.1164 g of Bi(NO3)3·5H2O and 0.028 g of NH4VO3 were dissolved in 60 mL of distilled water containing 1.6 mL of concentrated HNO3 (70 wt.%). Subsequently, 15 mL solution was transferred to a 50 mL Teflon-lined stainless steel autoclave, and the FTO substrate was immersed in the solution for hydrothermal reaction at 180°C for 12 hr. The resulting film was rinsed with
deionized water and finally calcined at 450°C for 2 hr in an air atmosphere to obtain a stable BiVO₄ thin film electrode.

(2) Preparation of BiVO₄-MoS₂ film: 0.026 g of diammoniumthiomyolydbate (NH₄)₂MoO₄, 0.149 g of potassium chloride (KCl) and 0.535 g of ammonium chloride (NH₄Cl) were dissolved in 50 mL of formamide to prepare an electrodeposition solution. Electrodeposition was carried out in a three-electrode system using CHI 660E electrochemical workstation (Chenhua, Shanghai). The BiVO₄ film was used as the working electrode. The titanium plate and the saturated Ag/AgCl were used as the counter electrode and reference electrode, respectively. The electrodeposition was performed at the voltage of −0.6 V for 15 min to obtain a BiVO₄-MoS₂ photocatalytic film.

(3) Preparation of BiVO₄-MoS₂-CO₃O₄ film: The BiVO₄-MoS₂ film was immersed in a 0.03 mol/L cobalt nitrate solution for 30 min and then taken out and annealed at 400°C for 1 hr under N₂ atmosphere to obtain the BiVO₄-MoS₂-CO₃O₄ photocatalytic film.

(4) Preparation of E-BiVO₄-MoS₂-CO₃O₄ film: According to the previous study of our group (Cong et al., 2020), electrochemical modification was carried out using a three-electrode system by a CHI 660E electrochemical workstation. The BiVO₄-MoS₂-CO₃O₄ film was used as the working electrode. The platinum plate and Ag/AgCl electrode were used as the counter electrode and the reference electrode, respectively. The electrolyte was 1 mol/L boric acid solution and pH was adjusted to 9.5 using potassium hydroxide. The film was treated at a voltage of −0.8 V for 15 sec to obtain a E-BiVO₄-MoS₂-CO₃O₄ photocatalytic film.

1.3. Characterization

X-ray diffraction (XRD) patterns were collected on a Bruker D8 advance powder diffract meter (D8 advance, Bruker AXS, Germany) at Cu-Kα (Test wavelength λ = 0.154056 nm) in the 2θ range of 10–70°. X-ray photoelectron spectroscopy (XPS, Thermo ESCALAB 250Xi spectrometer with Al-Kα at 1486.6 eV) was used to analyze the chemical composition and surface chemical state of the prepared samples (XLESCALAB 250Xi, Thermo fisher scientific, USA). The binding energy is corrected by C 1 s (284.6 eV). Scanning electron microscopy (SEM, Gemini SEM 500, ZEISS, Germany) was used to characterize the morphology, particle size and structure of the prepared catalytic films.

1.4. PEC measurements

PEC performance of the as-prepared film electrodes were all tested in the three-electrode system using CHI 660E electrochemical workstation. A xenon lamp with a UV 420 nm cutoff filter was used as an illumination source and the incident light intensity was 100 mW/cm². The platinum plate and Ag/AgCl electrode were used as the counter electrode and the reference electrode, respectively. The working electrode was the as-prepared thin film. Linear sweep voltammetry (LSV) was used to investigate the photocurrent densities of as-prepared photoelectrodes in 0.1 mol/L NaOH solution under dark/light conditions. Electrochemical impedance spectroscopy (EIS) was performed with an amplitude of 5 mV and a frequency of 0.01–10⁵ Hz at 0 V vs. Ag/AgCl. The monochromatic incident photon-to-electron conversion efficiency (IPCE) was measured in 0.1 mol/L Na₂SO₄ and 0.1 mol/L Na₂SO₃ mixed solution at 0.4 V vs. Ag/AgCl by a xenon lamp equipped with different monochromatic filters (400, 430, 475, 500, 550, and 600 nm).

1.5. PEC degradation of BPA

Bisphenol A (BPA) was used as a representative of emerging contaminants to investigate the degradation performance of the as-prepared films. The PEC degradation of BPA (10 mg/L) was carried out in a two-electrode system. The as-prepared film (active area 4 cm²) was used as the anode, and the titanium plate was used as the cathode. Na₂SO₄ (0.2 mol/L) was used as an electrolyte solution. Before the PEC reaction, the dark reaction was carried out for 30 min to achieve the adsorption-desorption equilibrium between BPA and the photocatalytic film. Then an appropriate voltage and visible light irradiation were applied to initiate the reaction. Similar to the steps of the above photoelectrocatalytic degradation experiment, different scavengers are added to the reaction solution to evaluate the active substances. Benzoquinone (10 mmol/L) is used to remove O₂−, 10 mmol/L oxalic acid is used to capture active hole (h⁺), and 10 mmol/L tert-butanol is used to remove HO₂. The concentration of BPA was determined by high-performance liquid chromatography (HPLC, Agilent1200 infinity, Agilent Corporation, USA) with Diamonsil C18 column and wavelength detection at 278 nm. A mixture of methanol and water (60:40) was used as the mobile phase. BPA removal rate (η) was calculated according to formula (1):

\[ \eta(\%) = (C_0 - C_t)/C_0 \times 100\% \]  

where \( C_0 \) (mg/L) and \( C_t \) (mg/L) represent the initial BPA concentration and the BPA concentration at reaction time t (min), respectively.

A total organic carbon analyzer (TOC-L CPN, Shimadzu, Japan) was used to evaluate the mineralization degree of the generated O₂−. The generation of O₂− was measured by electron spin resonance (ESR) spectroscopy (ESR A200, Bruker, Germany).

2. Results and discussion

2.1. Characterization

The morphologies of BiVO₄, BiVO₄-MoS₂, BiVO₄-MoS₂-CO₃O₄, and E-BiVO₄-MoS₂-CO₃O₄ were analyzed by SEM. As shown in Fig. 1a, the BiVO₄ is granular with the average width of 480 nm and the spatial structure is relatively tight. For BiVO₄-MoS₂, it can be seen from Fig. 1b that MoS₂ nanoparticles appear on the surface of BiVO₄. The average size of MoS₂ particles is 250 nm long and 150 nm wide. Fig. 1c shows the microstructure of BiVO₄-MoS₂-CO₃O₄ thin film electrode. More CO₃O₄ nanorods were found on the surface of BiVO₄-MoS₂. The length of the nanorod is ~200 nm. After electrochemical modification (Fig. 1d), E-BiVO₄-MoS₂-CO₃O₄ thin films become more compact, and the connections between the various structures are closer, this could probably facilitate charge transfer. The cross-sectional SEM test of the electrode film is
shown in Appendix A Fig. S2 and it can be seen that the thickness of the E-BiVO₄-MoS₂-Co₃O₄ film is 290.3 nm. In addition, the X-ray energy spectrum analysis (EDS) mapping test results (Appendix A Fig. S3) show that Co, O, Mo, Bi, S and V are homogeneously distributed over the thin film.

The phase structure and crystal structure of BiVO₄, BiVO₄-MoS₂, BiVO₄-MoS₂-Co₃O₄ and E-BiVO₄-MoS₂-Co₃O₄ thin film electrodes were analyzed by X-ray diffraction (XRD). In Fig. 2, the four catalytic materials all have characteristic peaks of BiVO₄, and the peaks at 18.7°, 19.1° and 29.0° correspond to the (101), (011) and (112) crystal planes in the BiVO₄ standard map (PDF 83-1700) (Su et al., 2011). It indicates that BiVO₄ is present in the composite photoelectric film. When MoS₂ was loaded on BiVO₄ film, the characteristic diffraction peaks at 15.1°, 34.8°, 39.96° and 58.38° were observed (Fig. 2b), which correspond to the (003), (012), (103) and (104) crystal planes in MoS₂ standard map (PDF 17-0744), respectively (Zhang et al., 2014; Sun et al., 2016). When Co₃O₄ was further loaded on BiVO₄-MoS₂, two peaks at 36.9° and 59.4° were observed, which correspond to the (311) and (511) crystal planes of Co₃O₄ (PDF 76-1802) (Zhao et al., 2018; Li et al., 2019), respectively. Therefore, MoS₂ and Co₃O₄ are co-loaded on the surface of BiVO₄.

The enlarged XRD pattern in the range of 28–32° is shown in Appendix A Fig. S4. The peak corresponding to 29° in the BiVO₄-MoS₂ electrode is weakened compared to that in BiVO₄ electrode, while the peak height at ~30.5° is enhanced, and the diffraction peak is obviously shifted to the lower degree. This may be due to the fact that during the preparation of BiVO₄-MoS₂, a voltage of ~0.6 V was used for electrodeposition, which might cause part of the BiVO₄ to be reduced and the peak shift to the lower degree. At the same time, this reduction also caused more exposure of the (040) crystal plane at 30.5° and a significant drop in the 29° peak corresponding to the (112) crystal plane. After the load of Co₃O₄ on BiVO₄-MoS₂,
the peaks shift to the original positions because the film was annealed at 400°C to obtain Co₃O₄ (Zhang et al., 2020).

To further investigate the surface chemical composition and valence state of the samples, XPS studies were performed on the E-BiVO₄-MoS₂-Co₃O₄ film electrode and the spectra were given in Fig. 3. XPS survey spectrum in Fig. 3a shows that six elements of Bi, V, O, Mo, S, and Co are present in the as-prepared E-BiVO₄-MoS₂-Co₃O₄ photoelectrode. Fig. 3b shows that the binding energies of Bi 4f½ and Bi 4f½ are 158.8 and 164.1 eV, respectively (Ge, 2008; Chatchai et al., 2009; Ye et al., 2016; Zhao et al., 2018; Hu et al., 2019). Compared with BiVO₄-MoS₂-Co₃O₄ (Appendix A Fig. S5a), the Bi 4f½ and Bi 4f½ peaks of E-BiVO₄-MoS₂-Co₃O₄ show a shift of 0.16 eV to lower binding energy, which indicates that E-BiVO₄-MoS₂-Co₃O₄ has more low-valent Bi ions. The binding energies of 516.4 and 523.9 eV of E-BiVO₄-MoS₂-Co₃O₄ in Fig. 3c were assigned to V 2p3/2 and V 2p1/2, which are lower than those of V⁵⁺ ions in BiVO₄ reported in the literature (V 2p3/2 517.4 eV and V 2p1/2 524.5 eV) (Hu et al., 2018). The peaks of V 2p of E-BiVO₄-MoS₂-Co₃O₄ in Appendix A Fig. S5b obviously show a shift of 0.08 eV to lower binding energy, indicating that some V⁵⁺ ions are reduced to V⁴⁺ after electrochemical modification (Wang et al., 2016, 2017; Hu et al., 2018; Zhao et al., 2018). Figs. 3b-c and S5b confirmed the existence of sub-stoichiometric BiVO₄. Fig. 3d shows the results of O 1 s analysis. Three distinct binding energies of 529.5 eV (O1), 531.5 eV (O2), and 532.1 eV (O3) correspond to O²⁻ species in the lattice (O1) (Sun et al., 2016; Ye et al., 2016), -OH bonded to metal cations in the anoxic zone to maintain charge balance (O2) (Fan et al., 2016; Wang et al., 2020) and H₂O (Wang et al., 2017), respectively. Compared with the O 1 s of BiVO₄-MoS₂-Co₃O₄ in Appendix A Fig. S5c, the proportion of O₂ in E-BiVO₄-MoS₂-Co₃O₄ has increased from 20.34% to 53.54% (Appendix A Table S1), which indicates that E-BiVO₄-MoS₂-Co₃O₄ has more oxygen vacancies relative to BiVO₄-MoS₂-Co₃O₄. The presence of oxygen vacancies can increase the carrier density and improve the charge separation in the film. The binding energies of 231.9 and 235.1 eV in Fig. 3e were assigned to the diffraction peaks of Mo 3d3/2 and Mo 3d5/2, which are the typical values of Mo⁴⁺ in MoS₂ (Sun et al., 2016; Ye et al., 2016; Lin et al., 2019; Liu et al., 2020). The diffraction peaks at 780.8 and 796.9 eV in Fig. 3f represent Co 2p3/2 and Co 2p1/2 (Yan et al., 2010; Shi et al., 2012; Xiang et al., 2013; Hu et al., 2019; Li et al., 2020). The peak of Co 2p3/2 in E-BiVO₄-MoS₂-Co₃O₄ is lower than that in BiVO₄-MoS₂-Co₃O₄ (Co 2p3/2 781.3 eV shown in Appendix A Fig. S5d). This may be due to the presence of oxygen vacancies and the formation of sub-stoichiometric oxides, which is consistent with the previous XPS analysis of Bi 4f, V 2p and O 1 s. The XPS results confirmed that electrochemical treatment can generate oxygen vacancies and cause oxygen species to re-coordinate to produce sub-stoichiometric oxides.

Appendix A Fig. S6a shows the UV–Vis spectrum of BiVO₄ and E-BiVO₄-MoS₂-Co₃O₄ films. It can be seen that the absorbance edge of the photoelectrocatalytic material prepared in this study is about 540 nm. There is almost no absorbance in the light range more than 550 nm. The E-BiVO₄-MoS₂-Co₃O₄ film has stronger light absorption than BiVO₄, indicating that electrochemical modification and heterojunction composite have a certain promotion effect on light absorption. The bandgap can be estimated by the Kubelka-Munk function according to formula (2):

$$e^\frac{-\alpha}{n} = \frac{A(hv - E_g)}{A}$$

where $\alpha$ is the absorption coefficient, $h$ (4.136 x 10⁻¹⁵ eV·sec) is the Planck constant, $v$ is the speed of light ($3 \times 10^8$ m/sec), $c$ is the constant (c = 1), and $E_g$ (eV) is the bandgap energy. The parameter $n$ depends on the characteristics of the transition in a semiconductor, where $n = 1/2$ for direct transitions and $n = 2$ for indirect transitions. As BiVO₄ is a direct band gap energy semiconductor (Regmi et al., 2019), the value of $n = 1/2$. As shown in Appendix A Fig. S6b, the bandgaps of BiVO₄ and E-BiVO₄-MoS₂-Co₃O₄ are approximately 2.36 and 2.34 eV, respectively. The results show that the composite catalytic material has a slightly narrower band gap, and can absorb more visible light.

2.2. PEC performance

The photocurrent properties of BiVO₄, BiVO₄-MoS₂, BiVO₄-MoS₂-Co₃O₄ and E-BiVO₄-MoS₂-Co₃O₄ films were tested by linear sweep voltammetry using 0.1 mol/L NaOH as electrolyte solution. As shown in Fig. 4, the photocurrent density of E-BiVO₄-MoS₂-Co₃O₄ film was 6.6 times higher than that of pure BiVO₄ at 0.45 V vs. Ag/AgCl under visible light irradiation.
Fig. 3 – X-ray photoelectron spectroscopy (XPS) spectra of E-BiVO₄-MoS₂-Co₃O₄ film electrode (a) survey spectrum and high-resolution core spectrum for (b) Bi 4f, (c) V 2p, (d) O 1s, (e) Mo 3d, and (f) Co 2p.

Fig. 4 – Linear sweep voltammetric curves of BiVO₄, BiVO₄-MoS₂, BiVO₄-MoS₂-Co₃O₄ and E-BiVO₄-MoS₂-Co₃O₄ films under (a) chopped visible and (b) UV–visible light irradiation in 0.1 mol/L NaOH aqueous solution.
The influence of electrochemical modification on the PEC performance of BiVO₄ can be seen in Appendix A Fig. S7. The photocurrents of BiVO₄ and BiVO₄-MoS₂O₄ have been significantly improved after electrochemical modification, which strongly supported that electrochemical modification is an effective approach to increase PEC activity of composite electrodes and sub-stoichiometric BiVO₄ formed by electrochemical modification may play an important role (Chen et al., 2011; Wang et al., 2016).

For further determination of charge separation properties, the charge recombination process in the as-prepared film electrodes was compared by testing the transient photocurrent according to formula (3):

\[
D = \frac{(I_t - I_{st})}{(I_{in} - I_{st})}
\]

where \(D\) represents transient photocurrent, \(I_{st}\) (mA/cm²) is photocurrent obtained at steady state, \(I_{in}\) (mA/cm²) and \(I_t\) (mA/cm²) photocurrent were measured at irradiation time of 0 and \(t\) (sec), respectively (Cong et al., 2018).

As shown in Fig. 5, the transient photocurrents of BiVO₄-MoS₂-Co₉O₄ and E-BiVO₄-MoS₂-Co₉O₄ films were compared at 0.5 V (vs. Ag/AgCl) under visible light irradiation. Among the tested samples, E-BiVO₄-MoS₂-Co₉O₄ exhibited the largest \(t\) value at the same \(D\) value. For example, at \(D = -1\), the \(t\) value was estimated to be ca. 1.55 sec for E-BiVO₄-MoS₂-Co₉O₄. Whereas, for BiVO₄-MoS₂-Co₉O₄ was 0.86 sec. Thus, the slowest recombination rate can be speculated in E-BiVO₄-MoS₂-Co₉O₄.

In order to further investigate the charge transfer process of the prepared electrode, the electrochemical impedance spectroscopy (EIS) of BiVO₄, BiVO₄-MoS₂, BiVO₄-MoS₂-Co₉O₄, and E-BiVO₄-MoS₂-Co₉O₄ films were measured. Fig. 6 shows that the impedance ring radius of BiVO₄-MoS₂-Co₉O₄ and E-BiVO₄-MoS₂-Co₉O₄ are smaller. And the impedance ring radius of E-BiVO₄-MoS₂-Co₉O₄ is the smallest, which indicates that it has the smallest charge transfer resistance among the as-prepared films. In addition, the equivalent circuit model (inset in Fig. 6) was used to simulate the Nyquist data, where \(R_s\) and \(R_a\) represent the series resistance and interface charge transfer resistance, respectively. According to Appendix A Table S2, the \(R_s\) values of BiVO₄, the \(R_a\) values of BiVO₄-MoS₂, BiVO₄-MoS₂-Co₉O₄ and E-BiVO₄-MoS₂-Co₉O₄ were detected by 3.3, 9.7 and 18.2 times, respectively, indicating that the composite material greatly enhanced the charge transfer efficiency.

The IPCE of BiVO₄, BiVO₄-MoS₂, BiVO₄-MoS₂-Co₉O₄ and E-BiVO₄-MoS₂-Co₉O₄ photoelectrodes at different wavelengths were measured to further investigate the PEC activity of as-prepared films. As shown in Appendix A Fig. S8, the IPCE curve trends of the four photoelectrocatalytic films are approximately the same in the absorption range from 400 to 550 nm. The IPCE values of BiVO₄-MoS₂, BiVO₄-MoS₂-Co₉O₄ and E-BiVO₄-MoS₂-Co₉O₄ films at 400 nm were about 16.5%, 26.1%, 28.5%, respectively, which were higher than that of BiVO₄ film (2.5%). It further proved that MoS₂, Co₉O₄ and electrochemical treatment can enhance charge separation and improve the PEC activity of BiVO₄.

Cyclic voltammetry (CV) analysis was used to calculate the double-layer capacitance of the material, and further evaluated the electrochemical active surface area (ECSA) of the prepared E-BiVO₄-MoS₂-Co₉O₄ electrode and BiVO₄ electrode through the double-layer capacitance (\(C_{dl}\)) specific capacitance (\(C_s\)) (Chen et al., 2019; Liu et al., 2019). As shown in Appendix A Fig. S9, the electrochemical active area of E-BiVO₄-MoS₂-Co₉O₄ (\(C_{dl} = 0.5195 \text{ mF/cm}^2\)) is much larger than that of BiVO₄ (\(C_{dl} = 0.0448 \text{ mF/cm}^2\)), which indicates that the prepared E-BiVO₄-MoS₂-Co₉O₄ electrode has larger electrochemical active area.
2.3. **PEC activity for the removal of refractory pollutants**

The removal of contaminants by the prepared E-BiVO₄-MoS₂-Co₃O₄ electrode was investigated using BPA as a simulated pollutant. As shown in Fig. 7, E-BiVO₄-MoS₂-Co₃O₄ film has better BPA removal efficiency than other PEC films. The degradation process was fitted using a pseudo first-order kinetic model. According to Appendix A Table S3, the reaction rate constant of E-BiVO₄-MoS₂-Co₃O₄ film is the largest among all electrodes, which is 3.22 times higher than BiVO₄. A total organic carbon analyzer (TOC) was used to evaluate the mineralization degree. The TOC removal rate is 61.5% under the optimal condition of BPA removal, which indicates the high mineralization of BPA. The PEC activity of E-BiVO₄-MoS₂-Co₃O₄ film for BPA removal was further investigated under PC, EC, and PEC conditions. Fig. 7b and Appendix A Table S4 show that the degradation rate of BPA under PC and EC conditions is lower than that of PEC. The reaction rate constant of PEC is 14.5 and 2 times that of PC and EC, respectively, which indicate that the degradation of BPA by E-BiVO₄-MoS₂-Co₃O₄ composite film has good efficiency in PEC process. The synergistic effect factor (f) was estimated to be about 75.76% for comparative experiments in the degradation process of BPA using the following definition:

$$f = \frac{k_{\text{PEC}} - (k_{\text{PC}} + k_{\text{EC}})}{(k_{\text{EC}} + k_{\text{PC}})} \times 100\%$$

where \(k_{\text{PEC}}\), \(k_{\text{EC}}\), and \(k_{\text{PC}}\) represent the reaction rate constants of BPA degradation under PEC, EC, and PC conditions, respectively.

The degradation intermediates of BPA were investigated by high performance liquid chromatography. Appendix A Fig. S10a is a high performance liquid chromatogram of the degradation of bisphenol A by E-BiVO₄-MoS₂-Co₃O₄ film. There are four intermediates which are hydroquinone, catechol, phenol, and 4-isopropylphenol in the degradation process of BPA (shown in Appendix A Fig. S10b). The intermediates will be further degraded with the reaction going on, and eventually be converted into inorganic substances CO₂ and H₂O.

The stability of E-BiVO₄-MoS₂-Co₃O₄ film was investigated by successive cyclic degradation experiments. As shown in Appendix A Fig. S11, the degradation rate of BPA remains basically unchanged after five cycles, which indicated that the E-BiVO₄-MoS₂-Co₃O₄ composite film has good stability.

2.4. **Proposed mechanism**

In order to investigate the main active species generated in the PEC degradation of BPA by E-BiVO₄-MoS₂-Co₃O₄ thin film, several scavengers (tert-butanol, oxalic acid, and p-benzoquinone) were used in degradation reaction. As shown in Fig. 8a, when 10 mmol/L p-benzoquinone (O₂⁻ scavenger) was added, the degradation efficiency of BPA decreased by 29.04%. When 10 mmol/L oxalic acid (h⁺ scavenger) was added, the degradation efficiency of BPA decreased by 62.27%. When 10 mmol/L t-butanol (HO· scavenger) was added, the removal rate of contaminants remained essentially the same, demonstrating that hydroxyl radicals are not the main active substances to oxidize BPA (Wang et al., 2010). From the above experimental results, it can be inferred that h⁺ and O₂⁻ are the main active species in the PEC degradation of BPA. Electron spin resonance (ESR) was used to further confirm the production of O₂⁻ during the photocatalytic degradation of BPA. As shown in Appendix A Fig. S12, no O₂⁻ signal is observed in the unexcited state, but there is a strong O₂⁻ signal after excitation, which means that O₂⁻ is indeed produced during the degradation of BPA.

On this basis, the mechanism of photocatalytic degradation of BPA by E-BiVO₄-MoS₂-Co₃O₄ composite photoelectro-catalytic film was further discussed. As shown in Fig. 8b, the conduction bands (CB) of BiVO₄ and MoS₂ are at 0.3 and -0.13 V, and the corresponding band gaps are 2.36 and 1.9 eV, respectively (Regmi et al., 2017; Zhang et al., 2017b). Under visible light irradiation (λ > 420 nm), electrons are excited from the valence band (VB) of BiVO₄ or MoS₂ to its corresponding conduction band (CB), forming photo-generated hole-electron pairs. The electrons of MoS₂ can be transferred to the CB of BiVO₄, while the holes in the VB of BiVO₄ migrate to the VB of MoS₂. Under the external applied potential, the electrons in CB of BiVO₄ could be driven to the cathode to reduce oxygen to generate O₂⁻. Thus, photogenerated electrons and holes were effectively separated. Holes accumulated on the VB of MoS₂ and the surface of Co₃O₄ could oxidize BPA, and finally gen-
erate inorganic substances such as CO₂ and H₂O (Appendix A Fig. S13). The main reactions in the degradation process of bisphenol A could be expressed as follows:

\[ \text{E-BiVO}_4\cdot\text{MoS}_2\cdot\text{Co}_3\text{O}_4 + h^+ \rightarrow \text{E-BiVO}_4\cdot\text{MoS}_2\cdot\text{Co}_3\text{O}_4 \ (\text{e}^- + \text{h}^+) \] (5)

\[ \text{e}^- + \text{O}_2 \rightarrow \text{O}_2^{2-} \] (6)

\[ 2\text{e}^- + \text{O}_2 + 2\text{H}^+ \rightarrow \text{H}_2\text{O}_2 \] (7)

\[ \text{H}_2\text{O}_2 + \text{e}^- \rightarrow \text{HO}^- + \text{OH}^- \] (8)

\[ \text{h}^+ + \text{OH}^- \rightarrow \text{HO}^- \] (9)

\[ \text{h}^+ + \text{bisphenol A} \rightarrow \text{degradation production} \] (10)

\[ \text{O}_2^{2-} + \text{bisphenol A} \rightarrow \text{degradation production} \] (11)

\[ \text{HO}^- + \text{bisphenol A} \rightarrow \text{degradation production} \] (12)

The degradation process of bisphenol A mainly includes three stages: (1) the mass transfer of organic compounds from the bulk solution to the electrode surface; (2) the adsorption of organic compounds at the catalytic site of electrode surface; (3) the reaction between the active material and the adsorbed organic molecules. According to the above reaction process and scavenger experiment, it can be seen that the main active substances in the reaction process are h⁺ and O₂²⁻. Since the life of h⁺ is very short, the reaction related to h⁺ mainly occurs on the electrode surface. The active e⁻ can react with dissolved oxygen in the solution to generate the corresponding active substance (O₂²⁻), which further react with organic compounds in bulk solution (Li et al., 2009). Under the synergetic action of h⁺, O₂²⁻ and HO⁻, BPA was effectively degraded.

3. Conclusions

E-BiVO₄·MoS₂·Co₃O₄ thin film electrodes with higher photocatalytic activity were synthesized by hydrothermal method, electrodeposition, and calcination. The photocurrent density of E-BiVO₄·MoS₂·Co₃O₄ film under visible light is 6.6 times that of BiVO₄ (0.45 V vs. Ag/AgCl). The E-BiVO₄·MoS₂·Co₃O₄ thin film electrode can effectively degrade organic pollutants and the degradation efficiency of BPA in PEC process is higher than that in PC or EC process. The reaction rate constant of E-BiVO₄·MoS₂·Co₃O₄ film is 3.53 times higher than that of BiVO₄. h⁺ and O₂²⁻ are the main active species in the PEC degradation of BPA. The enhanced PEC performance benefits from its lower interfacial charge transfer resistance, the formation of oxygen vacancies and sub-stoichiometric metal oxides, and higher separation efficiency of photogenerated electron-hole pairs, which effectively enhance the PEC activity of BiVO₄. Moreover, E-BiVO₄·MoS₂·Co₃O₄ composite film exhibited good stability.

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Appendix A. Supplementary data

Supplementary material associated with this article can be found in the online version at doi:10.1016/j.jes.2020.09.027.

REFERENCES


